19-4226; Rev 2; 9/10

EVALUATION KIT AVAILABLE

Dual-Channel, 10-Bit, 100Msps ADC

General Description

The MAX19516 dual-channel, analog-to-digital converter (ADC) provides 10-bit resolution and a maximum sample rate of 100Msps.

The MAX19516 analog input accepts a wide 0.4V to 1.4V input common-mode voltage range, allowing DCcoupled inputs for a wide range of RF, IF, and baseband front-end components. The MAX19516 provides excellent dynamic performance from baseband to high input frequencies beyond 400MHz, making the device ideal for zero-intermediate frequency (ZIF) and highintermediate frequency (IF) sampling applications. The typical signal-to-noise ratio (SNR) performance is 60dBFS and typical spurious-free dynamic range (SFDR) is 82dBc at $f_{IN} = 70MHz$ and $f_{CLK} = 100MHz$.

The MAX19516 operates from a 1.8V supply. Additionally, an integrated, self-sensing voltage regulator allows operation from a 2.5V to 3.3V supply (AVDD). The digital output drivers operate on an independent supply voltage (OVDD) over the 1.8V to 3.5V range. The analog power consumption is only 57mW per channel at VAVDD = 1.8V. In addition to low operating power, the MAX19516 consumes only 1mW in powerdown mode and 17mW in standby mode.

Various adjustments and feature selections are available through programmable registers that are accessed through the 3-wire serial-port interface. Alternatively, the serial-port interface can be disabled, with the three pins available to select output mode, data format, and clock-divider mode. Data outputs are available through a dual parallel CMOS-compatible output data bus that can also be configured as a single multiplexed parallel CMOS bus.

The MAX19516 is available in a small 7mm x 7mm 48pin thin QFN package and is specified over the -40°C to +85°C extended temperature range.

Refer to the MAX19505, MAX19506, and MAX19507 data sheets for pin- and feature-compatible 8-bit, 65Msps, 100Msps, and 130Msps versions, respectively. Refer to the MAX19515 and MAX19517 data sheets for pin- and feature-compatible 10-bit, 65Msps and 130Msps versions, respectively.

Applications

IF and Baseband Communications, Including Cellular Base Stations and Point-to-Point Microwave Receivers

Ultrasound and Medical Imaging

Portable Instrumentation and Low-Power Data

Digital Set-Top Boxes

Features

Very-Low-Power Operation (57mW/Channel at 100Msps)

- 1.8V or 2.5V to 3.3V Analog Supply
- Excellent Dynamic Performance
 60dBFS SNR at 70MHz
 82dBc SFDR at 70MHz
- ◆ User-Programmable Adjustments and Feature Selection through an SPI™ Interface
- Selectable Data Bus (Dual CMOS or Single Multiplexed CMOS)
- DCLK Output and Programmable Data Output Timing Simplifies High-Speed Digital Interface
- Very Wide Input Common-Mode Voltage Range (0.4V to 1.4V)
- Very High Analog Input Bandwidth (> 850MHz)
- Single-Ended or Differential Analog Inputs
- Single-Ended or Differential Clock Input
- Divide-by-One (DIV1), Divide-by-Two (DIV2), and Divide-by-Four (DIV4) Clock Modes
- Two's Complement, Gray Code, and Offset Binary Output Data Format
- Out-of-Range Indicator (DOR)
- CMOS Output Internal Termination Options (Programmable)
- Reversible Bit Order (Programmable)
- Data Output Test Patterns
- Small 7mm x 7mm 48-Pin Thin QFN Package with Exposed Pad

Ordering Information

PART	TEMP RANGE	PIN-PACKAGE
MAX19516ETM+	-40°C to +85°C	48 TQFN-EP*

+Denotes a lead(Pb)-free/RoHS-compliant package. *EP = Exposed pad.

Pin Configuration appears at end of data sheet.

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ABSOLUTE MAXIMUM RATINGS

OVDD, AVDD to GND0.3V to +3.6V
CMA, CMB, REFIO, INA+, INA-, INB+,
INB- to GND0.3V to +2.1V
CLK+, CLK-, SYNC, SPEN, CS, SCLK, SDIN
to GND0.3V to the lower of (VAVDD + 0.3V) and +3.6V
DCLKA, DCLKB, D9A–D0A, D9B–D0B, DORA, DORB
to GND0.3V to the lower of (VOVDD + 0.3V) and +3.6V

Continuous Power Dissipation ($T_A = +70^{\circ}C$)						
48-Pin Thin QFN, 7mm x 7mm x 0.8mm (de	erate 40mW/°C					
above +70°C)	3200mW					
Operating Temperature Range	40°C to +85°C					
Junction Temperature	+150°C					
Storage Temperature Range						
Lead Temperature (soldering, 10s)	+300°C					
Soldering Temperature (reflow)	+260°C					

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS

 $(V_{AVDD} = V_{OVDD} = 1.8V, internal reference, differential clock, V_{CLK} = 1.5V_{P-P}, f_{CLK} = 100MHz, A_{IN} = -0.5dBFS, data output termination = 50\Omega, T_A = -40^{\circ}C to +85^{\circ}C, unless otherwise noted. Typical values are at T_A = +25^{\circ}C.) (Note 1)$

PARAMETER	SYMBOL	CONDITIONS	MIN	ТҮР	MAX	UNITS
DC ACCURACY		•				
Resolution				10		Bits
Integral Nonlinearity	INL	f _{IN} = 3MHz	-0.8	±0.25	+0.8	LSB
Differential Nonlinearity	DNL	f _{IN} = 3MHz -0.7 ±0.2 +0.		+0.7	LSB	
Offset Error	OE	Internal reference	-0.4	±0.1	+0.4	%FS
Gain Error	GE	External reference = 1.25V	-1.5	±0.3	+1.5	%FS
ANALOG INPUTS (INA+, INA-, IN	B+, INB-) (Fig	gure 3)				
Differential Input-Voltage Range	VDIFF	Differential or single-ended inputs		1.5		VP-P
Common-Mode Input-Voltage Range	V _{CM}	(Note 2)	0.4		1.4	V
		Fixed resistance		> 100		
Input Resistance	R _{IN}	Differential input resistance, common mode connected to inputs		4		kΩ
Input Current	I _{IN}	Switched capacitance input current, each input		54		μA
	CPAR	Fixed capacitance to ground, each input	0.7		_	
Input Capacitance	CSAMPLE	Switched capacitance, each input		1.2		pF
CONVERSION RATE						
Maximum Clock Frequency	fCLK		100			MHz
Minimum Clock Frequency	fCLK				50	MHz
Data Latency		Figures 9, 10		9		Cycles

ELECTRICAL CHARACTERISTICS (continued)

 $(V_{AVDD} = V_{OVDD} = 1.8V, internal reference, differential clock, V_{CLK} = 1.5V_{P-P}, f_{CLK} = 100MHz, A_{IN} = -0.5dBFS, data output termination = 50\Omega, T_A = -40^{\circ}C to +85^{\circ}C, unless otherwise noted. Typical values are at T_A = +25^{\circ}C.) (Note 1)$

PARAMETER	SYMBOL	CONDITIONS	MIN	ТҮР	MAX	UNITS	
DYNAMIC PERFORMANCE	<u>.</u>						
Small-Signal Noise Floor	SSNF	f _{IN} = 70MHz, < -35dBFS		-60.3		dBFS	
		f _{IN} = 3MHz		60.1			
Signal-to-Noise Ratio	SNR	f _{IN} = 70MHz	58.9	60.0		dBFS	
		f _{IN} = 175MHz		59.7			
		f _{IN} = 3MHz		59.6			
Signal-to-Noise Plus Distortion Ratio	SINAD	f _{IN} = 70MHz	58.3	59.5		dB	
Hallo		$f_{IN} = 175 MHz$		59.2			
		f _{IN} = 3MHz		84			
Spurious-Free Dynamic Range (2nd and 3rd Harmonic)	SFDR1	f _{IN} = 70MHz	72.2	83		dBc	
		$f_{IN} = 175 MHz$		80			
Spurious-Free Dynamic Range (4th and Higher Harmonics)		$f_{IN} = 3MHz$		82			
	SFDR2	$f_{IN} = 70MHz$	74	82		dBc	
		$f_{IN} = 175 MHz$		82			
		f _{IN} = 3MHz		-84			
Second Harmonic	HD2	f _{IN} = 70MHz		-83	-72.2	dBc	
		$f_{IN} = 175 MHz$		-80			
		$f_{IN} = 3MHz$		-86			
Third Harmonic	HD3	$f_{IN} = 70MHz$		-86	-74	dBc	
		$f_{IN} = 175 MHz$		-82			
		f _{IN} = 3MHz		-80			
Total Harmonic Distortion	THD	f _{IN} = 70MHz		-79	-70.5	dBc	
		$f_{IN} = 175 MHz$		-77			
Third-Order Intermodulation	IM3	$f_{IN} = 70MHz \pm 1.5MHz$, -7dBFS		-90		dBc	
mild-Older merhodulation	11013	$f_{IN} = 175MHz \pm 2.5MHz$, -7dBFS		-80		UDC	
Full-Power Bandwidth	FPBW			850		MHz	
Aperture Delay	tad			850		ps	
Aperture Jitter	t _{AJ}			0.3		ps _{RMS}	
Overdrive Recovery Time		±10% beyond full scale		1		Cycles	

ELECTRICAL CHARACTERISTICS (continued)

 $(V_{AVDD} = V_{OVDD} = 1.8V, internal reference, differential clock, V_{CLK} = 1.5V_{P-P}, f_{CLK} = 100MHz, A_{IN} = -0.5dBFS, data output termination = 50\Omega, T_A = -40°C to +85°C, unless otherwise noted. Typical values are at T_A = +25°C.) (Note 1)$

PARAMETER	SYMBOL	CONDITIONS	MIN	ТҮР	МАХ	UNITS
INTERCHANNEL CHARACTERIS	TICS					
Orecetell		f_{INA} or $f_{INB} = 70$ MHz at -1dBFS		95		dDa
Crosstalk		f_{INA} or $f_{INB} = 175$ MHz at -1dBFS		85		dBc
Gain Match		f _{IN} = 70MHz		±0.05		dB
Offset Match		f _{IN} = 70MHz		±0.1		%FSR
Phase Match		$f_{IN} = 70MHz$		±0.5		Degrees
ANALOG OUTPUTS (CMA, CMB)						
CMA, CMB Output Voltage	VCOM	Default programmable setting	0.85	0.9	0.95	V
INTERNAL REFERENCE						
REFIO Output Voltage	V _{REFOUT}		1.23	1.25	1.27	V
REFIO Temperature Coefficient	TCREF			< ±60		ppm/°C
EXTERNAL REFERENCE						
REFIO Input-Voltage Range	VREFIN			1.25 +5/ -10%		V
REFIO Input Resistance	R _{REFIN}			10 ±20%		kΩ
CLOCK INPUTS (CLK+, CLK-)-	DIFFERENTI	AL MODE	1			1
Differential Clock Input Voltage				0.4 to 2.0		VP-P
Differential Input Common-Mode		Self-biased		1.2		
Voltage		DC-coupled clock signal		1.0 to 1.4		V
		Differential, default		10		kΩ
Input Resistance	RCLK	Differential, internal termination selected	100		Ω	
		Common mode	9		kΩ	
Input Capacitance	CCLK	To ground, each input		3		pF
CLOCK INPUTS (CLK+, CLK-)-S	SINGLE-END	ED MODE (V _{CLK-} < 0.1V)				
Single-Ended Mode Selection Threshold (V _{CLK} -)					0.1	V
Allowable Logic Swing (V _{CLK+})				0 - Vavdd		V
Single-Ended Clock Input High Threshold (V _{CLK+})			1.5			V
Single-Ended Clock Input Low Threshold (V _{CLK+})					0.3	V
Input Leakage (CLK+)		$V_{CLK+} = V_{AVDD} = 1.8V \text{ or } 3.3V$ $V_{CLK+} = 0V$	-0.5		+0.5	μA
Input Leakage (CLK-)		$V_{CLK-} = 0V$	-150		-50	μA
Input Capacitance (CLK+)				3		pF

ELECTRICAL CHARACTERISTICS (continued)

 $(V_{AVDD} = V_{OVDD} = 1.8V, internal reference, differential clock, V_{CLK} = 1.5V_{P-P}, f_{CLK} = 100MHz, A_{IN} = -0.5dBFS, data output termination = 50\Omega, T_A = -40^{\circ}C to +85^{\circ}C, unless otherwise noted. Typical values are at T_A = +25^{\circ}C.) (Note 1)$

PARAMETER	SYMBOL	CONDITIONS	MIN	ТҮР	MAX	UNITS	
CLOCK INPUTS (SYNC)	·	•	·			•	
Allowable Logic Swing			(0 - Vavde)	V	
Sync Clock Input High Threshold			1.5			V	
Sync Clock Input Low Threshold					0.3	V	
		V _{SYNC} = V _{AVDD} = 1.8V or 3.3V			+0.5		
Input Leakage		V _{SYNC} = 0V	-0.5			μA	
Input Capacitance				4.5		pF	
DIGITAL INPUTS (SHDN, SPEN)							
Allowable Logic Swing			(0 - Vavde)	V	
Input High Threshold			1.5			V	
Input Low Threshold					0.3	V	
		V _{SHDN} /V _{SPEN} = V _{AVDD} = 1.8V or 3.3V			+0.5		
Input Leakage		V _{SHDN} /V _{SPEN} = 0V	-0.5			μA	
Input Capacitance	CDIN			3		pF	
SERIAL-PORT INPUTS (SCLK, S	DIN, CS, whe	ere SPEN = 0V)—SERIAL-PORT CONTROL	MODE				
Allowable Logic Swing				0 - Vavde)	V	
Input High Threshold			1.5			V	
Input Low Threshold					0.3	V	
		$V_{SCLK}/V_{SDIN}/V_{\overline{CS}} = V_{AVDD} = 1.8V \text{ or } 3.3V$			+0.5		
Input Leakage		$V_{SCLK}/V_{SDIN}/V_{\overline{CS}} = 0V$	-0.5			μA	
Input Capacitance	CDIN			3		pF	
SERIAL-PORT INPUTS (SCLK, S	DIN, CS, whe	ere SPEN = V _{AVDD})—PARALLEL CONTROL	MODE (Fig	gure 5)			
		$V_{SCLK}/V_{SDIN}/V_{\overline{CS}} = V_{AVDD} = 1.8V$	7	12	17		
Input Pullup Current		$V_{SCLK}/V_{SDIN}/V_{\overline{CS}} = V_{AVDD} = 3.3V$	16	21	26	μA	
Input Bulldown Current		$V_{SCLK}/V_{SDIN}/V_{\overline{CS}} = 0V, V_{AVDD} = 1.8V$	-65	-50	-35		
Input Pulldown Current		$V_{SCLK}/V_{SDIN}/V_{\overline{CS}} = 0V, V_{AVDD} = 3.3V$	-105	-90	-75	μA	
Open Circuit Veltage	Vee	V _{AVDD} = 1.8V	1.35	1.45	1.55	V	
Open-Circuit Voltage	Voc	$V_{AVDD} = 3.3V$	2.58	2.58 2.68 2.78		V	
DIGITAL OUTPUTS (75Ω, D0–D9	(A and B Ch	annel), DCLKA, DCLKB, DORA, DORB)					
Output-Voltage Low	V _{OL}	I _{SINK} = 200μA			0.2	V	
Output-Voltage High	Voн	ISOURCE = 200µA	Vovdd - 0.2			V	
Three Otate Leeks 75 Ourses	L.	V _{OVDD} applied			+0.5).5 μA	
Three-State Leakage Current	ILEAK	GND applied	-0.5				

ELECTRICAL CHARACTERISTICS (continued)

 $(V_{AVDD} = V_{OVDD} = 1.8V, internal reference, differential clock, V_{CLK} = 1.5V_{P-P}, f_{CLK} = 100MHz, A_{IN} = -0.5dBFS, data output termination = 50\Omega, T_A = -40°C to +85°C, unless otherwise noted. Typical values are at T_A = +25°C.) (Note 1)$

PARAMETER	SYMBOL	CONDITIONS	MIN	ТҮР	МАХ	UNITS
POWER-MANAGEMENT CHARA	CTERISTICS	•	·			•
Wake-Up Time from Shutdown	twake	Internal reference, $C_{REFIO} = 0.1 \mu F (10\tau)$		5		ms
Wake-Up Time from Standby	twake	Internal reference		15		μs
SERIAL-PORT INTERFACE TIMIN	IG (Note 2) (Figure 7)				
SCLK Period	t SCLK		50			ns
SCLK to $\overline{\text{CS}}$ Setup Time	tcss		10			ns
SCLK to \overline{CS} Hold Time	tсsн		10			ns
SDIN to SCLK Setup Time	tsds	Serial-data write	10			ns
SDIN to SCLK Hold Time	tsdh	Serial-data write	0			ns
SCLK to SDIN Output Data Delay	tsdd	Serial-data read			10	ns
TIMING CHARACTERISTICS-DU	JAL BUS PA	RALLEL MODE (Figure 9) (Default Timing, s	see Table	5)		
Clock Pulse-Width High	tсн			5.0		ns
Clock Pulse-Width Low	tCL			5.0		ns
Clock Duty Cycle	tCH/tCLK			30 to 70		%
Data Delay After Rising Edge of	1	C _L = 10pF, V _{OVDD} = 1.8V (Note 2)	2.1	4.0	5.8	
CLK+	tDD	C _L = 10pF, V _{OVDD} = 3.3V		3.1		ns
Data to DCLK Setup Time	t SETUP	C _L = 10pF, V _{OVDD} = 1.8V (Note 2)	8.1	8.7		ns
Data to DCLK Hold Time	thold	C _L = 10pF, V _{OVDD} = 1.8V (Note 2)	0.6	1.3		ns
TIMING CHARACTERISTICS-MU	JLTIPLEXED	BUS PARALLEL MODE (Figure 10) (Defaul	lt Timing,	see Table	5)	
Clock Pulse-Width High	tсн			5.0		ns
Clock Pulse-Width Low	tCL			5.0		ns
Clock Duty Cycle	tCH/tCLK			30 to 70		%
Data Delay After Rising Edge of	1	C _L = 10pF, V _{OVDD} = 1.8V (Note 2)	2.1	3.9	5.8	
CLK+	tDD	$C_L = 10 pF, V_{OVDD} = 3.3 V$		3.1		ns
Data to DCLK Setup Time	t SETUP	$C_{L} = 10 pF, V_{OVDD} = 1.8V (Note 2)$	2.9	3.9		ns
Data to DCLK Hold Time	thold	$C_L = 10 pF$, $V_{OVDD} = 1.8V$ (Note 2)	0.4	1.1		ns
DCLK Duty Cycle	tDCH/tCLK	$C_L = 10 pF$, $V_{OVDD} = 1.8V$ (Note 2)	41	50	59	%
MUX Data Duty Cycle	tCHA/tCLK	$C_L = 10 pF$, $V_{OVDD} = 1.8V$ (Note 2)	41	50	59	%
TIMING CHARACTERISTICS—SY	NCHRONIZ	ATION (Figure 12)				
Setup Time for Valid Clock Edge	tsuv	Edge mode (Note 2)	0.7			ns
Hold-Off Time for Invalid Clock Edge	tно	Edge mode (Note 2)	0.5			ns
Minimum Synchronization Pulse Width		Relative to input clock period		2		Cycles

ELECTRICAL CHARACTERISTICS (continued)

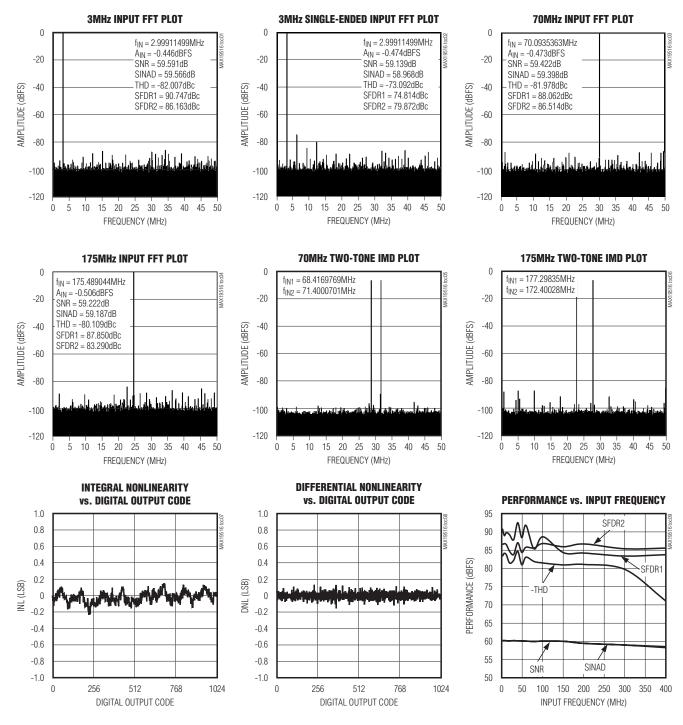
 $(V_{AVDD} = V_{OVDD} = 1.8V, internal reference, differential clock, V_{CLK} = 1.5V_{P-P}, f_{CLK} = 100MHz, A_{IN} = -0.5dBFS, data output termination = 50\Omega, T_A = -40^{\circ}C to +85^{\circ}C, unless otherwise noted. Typical values are at T_A = +25^{\circ}C.) (Note 1)$

PARAMETER	SYMBOL	CONDITIONS	MIN	ТҮР	MAX	UNITS	
POWER REQUIREMENTS		•					
		Low-level VAVDD	1.7		1.9		
Analog Supply Voltage	VAVDD	High-level V _{AVDD} (regulator mode, invoked automatically)	2.3		3.5	V	
Digital Output Supply Voltage	V _{OVDD}		1.7		3.5	V	
Analog Supply Current		Dual channel		63	77		
		Single channel active		37		mA	
	IAVDD	Standby mode		9.5	13		
		Power-down mode		0.65	0.9		
		Power-down mode, $V_{AVDD} = 3.3V$		1.6		1	
		Dual channel		113	139		
		Dual channel, $V_{AVDD} = 3.3V$		208			
Angles Dewer Dissignation	D	Single channel active		67		mW	
Analog Power Dissipation	Pda	Standby mode		17	24	TTIVV	
		Power-down mode		1.2	1.6		
		Power-down mode, V _{AVDD} = 3.3V		2.9			
Digital Quitaut Quantu Quirant	1	Dual-channel mode, $C_L = 10pF$		20			
Digital Output Supply Current	IOVDD	Power-down mode		< 0.1		mA	

Note 1: Specifications \ge +25°C guaranteed by production test, specifications < +25°C guaranteed by design and characterization. **Note 2:** Guaranteed by design and characterization.

tion = 50Ω , T_A = +25°C, unless otherwise noted.)

Dual-Channel, 10-Bit, 100Msps ADC

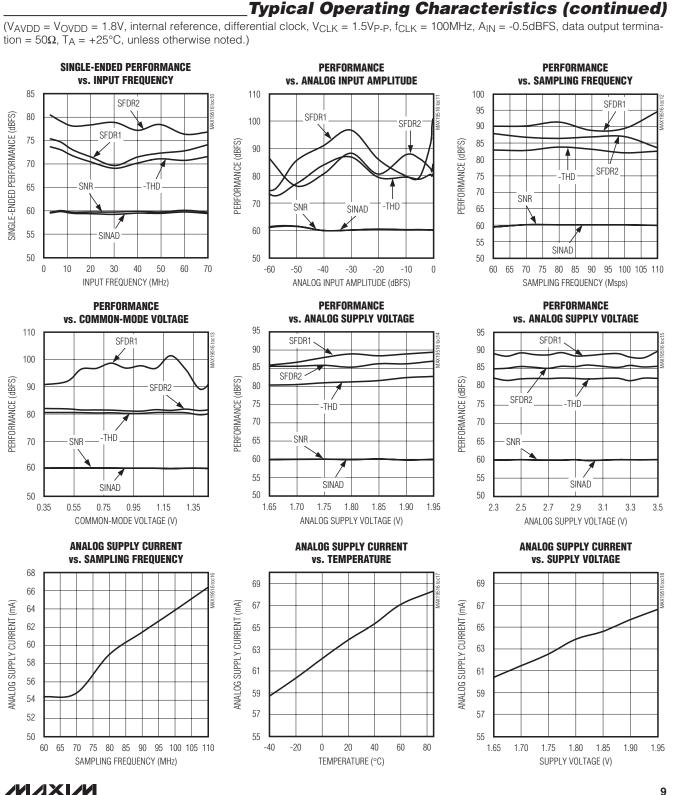


(VAVDD = VOVDD = 1.8V, internal reference, differential clock, VCLK = 1.5VP-P, fCLK = 100MHz, AIN = -0.5dBFS, data output termina-

Typical Operating Characteristics





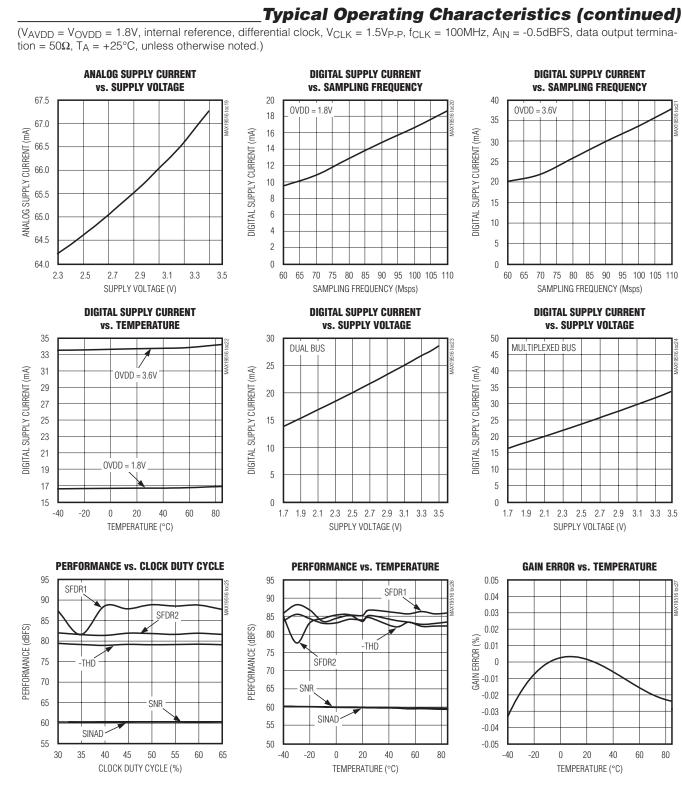


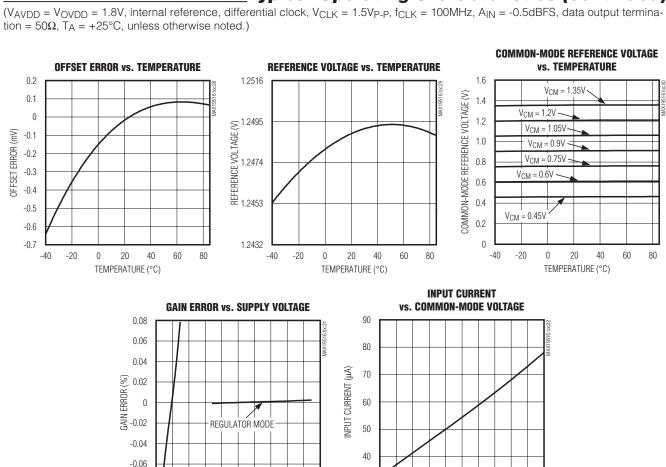
MAX19516

9

MAX19516

Dual-Channel, 10-Bit, 100Msps ADC





30

0.4 0.5 0.6 0.7 0.8 0.9 1.0 1.1 1.2 1.3 1.4

COMMON-MODE VOLTAGE (V)

Typical Operating Characteristics (continued)

tion = 50Ω , T_A = +25°C, unless otherwise noted.)

-0.08

1.6 1.8 2.0 2.2 2.4 2.6 2.8 3.0 3.2 3.4 3.6

SUPPLY VOLTAGE (V)

11

MAX19516

_Pin Description

PIN	NAME	FUNCTION
1, 12, 13, 48	AVDD	Analog Supply Voltage. Bypass each AVDD input pair (1, 48) and (12, 13) to GND with 0.1µF.
2	CMA	Channel A Common-Mode Input-Voltage Reference
3	INA+	Channel A Positive Analog Input
4	INA-	Channel A Negative Analog Input
5	SPEN	Active-Low SPI Enable. Drive high to enable parallel programming mode.
6	REFIO	Reference Input/Output. To use internal reference, bypass to GND with a > 0.1µF capacitor. See the <i>Reference Input/Output (REFIO)</i> section for external reference adjustment.
7	SHDN	Active-High Power-Down. If SPEN is high (parallel programming mode), a register reset is initiated on the falling edge of SHDN.
8	I.C.	Internally Connected. Leave unconnected.
9	INB+	Channel B Positive Analog Input
10	INB-	Channel B Negative Analog Input
11	CMB	Channel B Common-Mode Input-Voltage Reference
14	SYNC	Clock-Divider Mode Synchronization Input
15	CLK+	Clock Positive Input
16	CLK-	Clock Negative Input. If CLK- is connected to ground, CLK+ is a single-ended logic-level clock input. Otherwise, CLK+/CLK- are self-biased differential clock inputs.
17, 18	GND	Ground. Connect all ground inputs and EP (exposed pad) together.
19	DORB	Channel B Data Over Range
20	DCLKB	Channel B Data Clock
21	D0B	Channel B Three-State Digital Output, Bit 0 (LSB)
22	D1B	Channel B Three-State Digital Output, Bit 1
23	D2B	Channel B Three-State Digital Output, Bit 2
24	D3B	Channel B Three-State Digital Output, Bit 3
25, 36	OVDD	Digital Supply Voltage. Bypass each OVDD input to GND with 0.1µF capacitor.
26	D4B	Channel B Three-State Digital Output, Bit 4
27	D5B	Channel B Three-State Digital Output, Bit 5
28	D6B	Channel B Three-State Digital Output, Bit 6
29	D7B	Channel B Three-State Digital Output, Bit 7
30	D8B	Channel B Three-State Digital Output, Bit 8
31	D9B	Channel B Three-State Digital Output, Bit 9 (MSB)
32	D0A	Channel A Three-State Digital Output, Bit 0 (LSB)
33	D1A	Channel A Three-State Digital Output, Bit 1
34	D2A	Channel A Three-State Digital Output, Bit 2
35	D3A	Channel A Three-State Digital Output, Bit 3
37	D4A	Channel A Three-State Digital Output, Bit 4
38	D5A	Channel A Three-State Digital Output, Bit 5
39	D6A	Channel A Three-State Digital Output, Bit 6

Pin Description (continued)

PIN	NAME	FUNCTION
40	D7A	Channel A Three-State Digital Output, Bit 7
41	D8A	Channel A Three-State Digital Output, Bit 8
42	D9A	Channel A Three-State Digital Output, Bit 9 (MSB)
43	DORA	Channel A Data Over Range
44	DCLKA	Channel A Data Clock
45	SDIN/FORMAT	SPI Data Input/Format. Serial-data input when SPEN is low. Output data format when SPEN is high.
46	SCLK/DIV	Serial Clock/Clock Divider. Serial clock when SPEN is low. Clock divider when SPEN is high.
47	CS/OUTSEL	Serial-Port Select/Data Output Mode. Serial-port select when SPEN is low. Data output mode selection when SPEN is high.
_	EP	Exposed Pad. Internally connected to GND. Connect to a large ground plane to maximize thermal performance.

Detailed Description

The MAX19516 uses a 10-stage, fully differential, pipelined architecture (Figure 1) that allows for highspeed conversion while minimizing power consumption. Samples taken at the inputs move progressively through the pipeline stages every half clock cycle. From input to output the total latency is 9 clock cycles. Each pipeline converter stage converts its input voltage to a digital output code. At every stage, except the last, the error between the input voltage and the digital output code is multiplied and passed on to the next pipeline stage. Digital error correction compensates for ADC comparator offsets in each pipeline stage and ensures no missing codes. Figure 2 shows the MAX19516 functional diagram.

Analog Inputs and Common-Mode Reference

Apply the analog input signal to the analog inputs (INA+/INA- or INB+/INB-), which are connected to the input sampling switch (Figure 3). When the input sampling switch is closed, the input signal is applied to the sampling capacitors through the input switch resistance. The input signal is sampled at the instant the input switch opens. The pipeline ADC processes the sampled voltage and the digital output result is available 9 clock cycles later. Before the input switch is closed to begin the next sampling cycle, the sampling capacitors are reset to the input common-mode potential.

Common-mode bias can be provided externally or internally through $2k\Omega$ resistors. In DC-coupled applications, the signal source provides the external bias and the bias current. In AC-coupled applications, the input

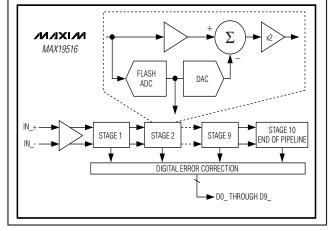


Figure 1. Pipeline Architecture—Stage Blocks

current is supplied by the common-mode input voltage. For example, the input current can be supplied through the center tap of a transformer secondary winding. Alternatively, program the appropriate internal register through the serial-port interface to supply the input DC current through internal $2k\Omega$ resistors (Figure 3). When the input current is supplied through the internal resistors, the input common-mode potential is reduced by the voltage drop across the resistors. The common-mode input reference voltage can be adjusted through programmable register settings from 0.45V to 1.35V in 0.15V increments. The default setting is 0.90V. Use this feature to provide a common-mode output reference to a DC-coupled driving circuit.

MAX19516

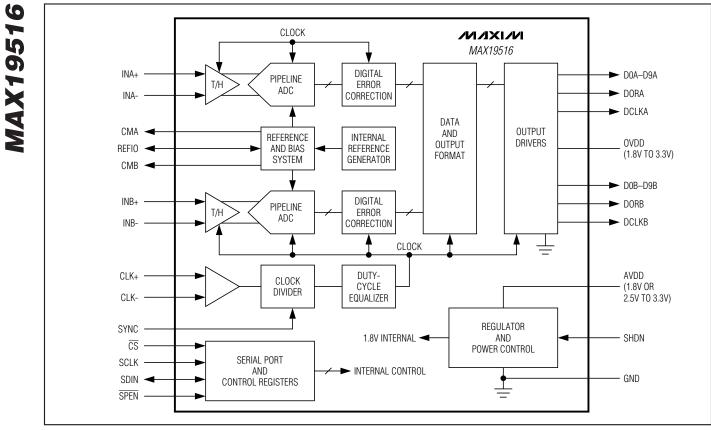


Figure 2. Functional Diagram

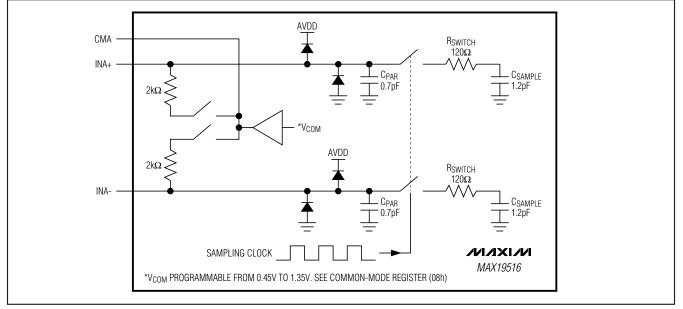


Figure 3. Internal Track-and-Hold (T/H) Circuit

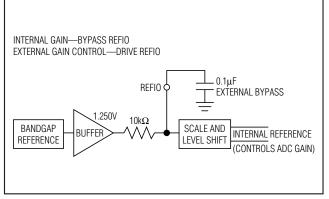


Figure 4. Simplified Reference Schematic

Table 1. Parallel-Interface Pin Functionality

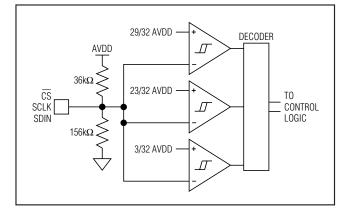


Figure 5. Simplified Parallel-Interface Input Schematic

Table I. Pa	able 1. Parallel-Interface Pin Functionality								
SPEN	SDIN/FORMAT	SCLK/DIV	CS/OUTSEL	DESCRIPTION					
0	SDIN	SCLK	CS	SPI interface active. Features are programmed through the serial port (see the <i>Serial Programming Interface</i> section).					
1	0	Х	Х	Two's complement					
1	AVDD	Х	Х	Offset binary					
1	Unconnected	Х	Х	Gray code					
1	Х	0	Х	Clock divide-by-1					
1	Х	AVDD	Х	Clock divide-by-2					
1	Х	Unconnected	Х	Clock divide-by-4					
1	Х	Х	0	CMOS (dual bus)					
1	Х	Х	AVDD	MUX CMOS (channel A data bus)					
1	Х	Х	Unconnected	MUX CMOS (channel B data bus)					

X = Don't care.

Reference Input/Output (REFIO)

REFIO adjusts the reference potential, which, in turn, adjusts the full-scale range of the ADC. Figure 4 shows a simplified schematic of the reference system. An internal bandgap voltage generator provides an internal reference voltage. The bandgap potential is buffered and applied to REFIO through a 10k Ω resistor. Bypass REFIO with a 0.1µF capacitor to GND. The bandgap voltage is applied to a scaling and level-shift circuit, which creates internal reference potentials that establish the full-scale range of the ADC. Apply an external voltage on REFIO to trim the ADC full scale. The allowable adjustment range is +5/-15%. The REFIO-to-ADC gain transfer function is:

VFS = 1.5 x [VREFIO/1.25] Volts

Programming and Interface

There are two ways to control the MAX19516 operating modes. Full feature selection is available using the SPI interface, while the parallel interface offers a limited set of commonly used features. The programming mode is selected using the SPEN input. Drive SPEN low for SPI interface; drive SPEN high for parallel interface.

Parallel Interface

The parallel interface offers a pin-programmable interface with a limited feature set. Connect SPEN to AVDD to enable the parallel interface. See Table 1 for pin functionality; see Figure 5 for a simplified parallel-interface input schematic.

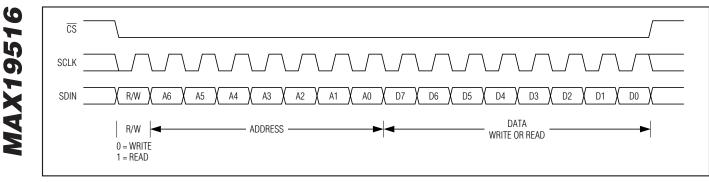


Figure 6. Serial-Interface Communication Cycle

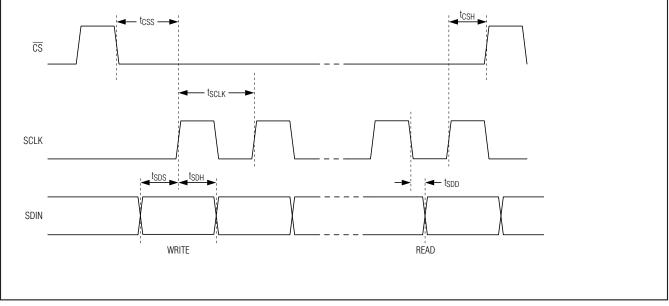


Figure 7. Serial-Interface Timing Diagram

Serial Programming Interface

A serial interface programs the MAX19516 control registers through the \overline{CS} , SDIN, and SCLK inputs. Serial data is shifted into SDIN on the rising edge of SCLK when \overline{CS} is low. The MAX19516 ignores the data presented at SDIN and SCLK when \overline{CS} is high. \overline{CS} must transition high after each read/write operation. SDIN also serves as the serial-data output for reading control registers. The serial interface supports two-byte transfer in a communication cycle. The first byte is a control byte, containing the address and read/write instruction, written to the MAX19516. The second byte is a data byte and can be written to or read from the MAX19516.

Figure 6 shows a serial-interface communication cycle. The first SDIN bit clocked in establishes the communi-

cation cycle as either a write or read transaction (0 for write operation and 1 for read operation). The following 7 bits specify the address of the register to be written or read. The final 8 SDIN bits are the register data. All address and data bits are clocked in or out MSB first. During a read operation, the MAX19516 serial port drives read data (D7) into SDIN after the falling edge of SCLK following the 8th rising edge of SCLK. Since the minimum hold time on SDIN input is zero, the master can stop driving SDIN any time after the 8th rising edge of SCLK. Subsequent data bits are driven into SDIN on the falling edge of SCLK. Output data in a read operation is latched on the rising edge of SCLK. Figure 7 shows the detailed serial-interface timing diagram. 查询"MAX19516"供应商

Register address 0Ah is a special-function register. Writing data 5Ah to register 0Ah initiates a register reset. When this operation is executed, all control registers are reset to default values. A read operation of register 0Ah returns a status byte with information described in Table 2.

User-Programmable Registers

Dual-Channel, 10-Bit, 100Msps ADC

BIT NO.	VALUE	DESCRIPTION				
7	0	Reserved				
6	0	served				
5	0 or 1	ROM read in progress				
4	0 or 1	1 = ROM read completed and register data is valid (checksum is OK)				
3	0	Reserved				
2	1	Reserved				
1	0 or 1	Reserved				
0	0 or 1	1 = Duty-cycle equalizer DLL is locked				

Table 2. Register 0Ah Status Byte

Table 3. User-Programmable Registers

ADDRESS	POR DEFAULT	FUNCTION
00h	00000011	Power management
01h	0000000	Output format
02h	00000000	Digital output power management
03h	10110110	Data/DCLK timing
04h	00000000	CHA data output termination control
05h	00000000	CHB data output termination control
06h	00000000	Clock divide/data format/test pattern
07h	Reserved	Reserved—do not use
08h	00000000	Common mode
0Ah	—	Software reset

Power Management (00h)

BIT 7	BIT 6	BIT 5	BIT 4	BIT 3	BIT 2	BIT 1	BIT 0
HPS_SHDN1	STBY_SHDN1	CHB_ON_SHDN1	CHA_ON_SHDN1	HPS_SHDN0	STBY_SHDN0	CHB_ON_SHDN0	CHA_ON_SHDN0

The SHDN input (pin 7) toggles between any two power-management states. The Power Management register defines each power-management state. In the default state, SHDN = 1 shuts down the MAX19516 and SHDN = 0 returns to full power.

In addition to power management, the HPS_SHDN1 and HPS_SHDN0 activate an A+B adder mode. In this mode, the results from both channels are averaged.

The MUX_CH bit selects which bus the (A+B)/2 data is presented.

Control Bits:

HPS_SHDN0	STBY_SHDN0	CHA_ON_SHDN0	CHB_ON_SHDN0	SHDN INPUT = 0*	
HPS_SHDN1	STBY_SHDN1	CHA_ON_SHDN1	CHB_ON_SHDN1	SHDN INPUT = 1**	
Х	0	0	0	Complete power-down	
0	0	0	1	Channel B active, channel A full power-down	
0	0	1	0 Channel A active, channel B full power-dow		
0	Х	1	1 Channels A and B active		
0	1	0	0	Channels A and B in standby mode	
0	1	0	1	Channel B active, channel A standby	
0	1	1	0	Channel A active, channel B standby	
1	1	0	0 Channels A and B in standby mode		
1	Х	Х	1 Channels A and B active, output is averag		
1	Х	1	Х	Channels A and B active, output is averaged	

*HPS_SHDN0, STBY_SHDN0, CHA_ON_SHDN0, and CHB_ON_SHDN0 are active when SHDN = 0.

**HPS_SHDN1, STBY_SHDN1, CHA_ON_SHDN1, and CHB_ON_SHDN1 are active when SHDN = 1.

X = Don't care.

Note: When HPS_SHDN_ = 1 (A+B adder mode), CHA_ON_SHDN_ and CHB_ON_SHDN_ must **BOTH** equal 0 for power-down or standby.

Output Format (01h)

BIT 7	BIT 6	BIT 5	BIT 4	BIT 3	BIT 2	BIT 1	BIT 0
0	0	0	BIT_ORDER_B	BIT_ORDER_A	MUX_CH	MUX	0

- Bit 7, 6, 5 Set to 0 for proper operation Bit 4 BIT_ORDER_B: Reverse CHB output bit order 0 = Defined data bus pin order (default)
 - 1 = Reverse data bus pin order
- Bit 3 BIT_ORDER_A: Reverse CHA output bit order
 - 0 = Defined data bus pin order (default)
 - 1 = Reverse data bus pin order
- Bit 2 MUX_CH: Multiplexed data bus selection
 - 0 = Multiplexed data output on CHA (CHA data presented first, followed by CHB data) (default)
 - 1 = Multiplexed data output on CHB (CHB data presented first, followed by CHA data)
- Bit 1 MUX: Digital output mode
 - 0 = Dual data bus output mode (default)
 - 1 = Single multiplexed data bus output mode
 - MUX_CH selects the output bus
- Bit 0 Set to 0 for proper operation

BIT 7	BIT 6	;	BIT 5	BIT 4	BIT 3	BIT 2	BIT 1	BIT 0	
Х	Х		Х	Х	PD_DOUT_1	PD_DOUT_0	DIS_DOR	DIS_DCLK	
Bit 7–4	Don't care								
Bit 3, 2	2 PD_DOUT_1, PD_DOUT_0: Power-down digital output state control								
	00 = Digital	outpu	ut three state (default)					
	01 = Digital	outpu	ut low						
	10 = Digital	outpu	ut three state						
	11 = Digital	outpu	ut high						
Bit 1	DIS_DOR: [DOR d	lriver disable						
	0 = DOR active (default)								
	1 = DOR disabled (three state)								
Bit 0	DIS_DCLK: DCLK driver disable								
	0 = DCLK a	ctive	(default)						
	1 = DCLK disabled (three state)								

Digital Output Power Management (02h)

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Dual-Channel, 10-Bit, 100Msps ADC

Data/DCLK Timing (03h)

BIT 7	BIT 6	BIT 5	BIT 4	BIT 3	BIT 2	BIT 1	BIT 0
DA_BYPAS	SS DLY_HALF_T	DCLKTIME_2	DCLKTIME_1	DCLKTIME_0	DTIME_2	DTIME_1	DTIME_0
Bit 7	DA_BYPASS: Da	ta aligner bypa	ISS				
	0 = Nominal						
	1 = Bypasses da Rising clock			mize output da nately 6ns with			
Bit 6	DLY_HALF_T: Da	ata and DCLK (delayed by T/2				
	0 = Normal, no d	elay (default)					
	1 = Delays data a	and DCLK outp	outs by T/2				
	Disabled in N	/IUX data bus r	node				
Bit 5, 4, 3	DCLKTIME_2, DO	CLKTIME_1, D	CLKTIME_0: D	CLK timing adj	ust (controls bo	oth channels)	
	000 = Nominal						
	001 = +T/16						
	010 = +2T/16						
	011 = +3T/16						
	100 = Reserved,	do not use					
	101 = -1T/16						
	110 = -2T/16 (de	fault)					
	111 = -3T/16						
Bit 2, 1, 0	DTIME_2, DTIME	_1, DTIME_0: I	Data timing ad	just (controls be	oth channels)		
	000 = Nominal						
	001 = +T/16						
	010 = +2T/16						
	011 = +3T/16						
	100 Decerved	do pot upo					

- 100 = Reserved, do not use
- 101 = -1T/16
- 110 = -2T/16 (default)
- 111 = -3T/16

CHA Data Output Termination Control (04h)

BIT 7	BIT 6	BIT 5	BIT 4	BIT 3	BIT 2	BIT 1	BIT 0			
Х	Х	CT_DCLK_2_A	CT_DCLK_1_A	CT_DCLK_0_A	CT_DATA_2_A	CT_DATA_1_A	CT_DATA_0_A			
Bit 7, 6	Don't ca	Don't care								
Bit 5, 4, 3	CT_DCL	_K_2_A, CT_DCL	K_1_A, CT_DCL	_K_0_A: CHA D0	CLK termination	control				
	000 = 5	0 Ω (default)								
	001 = 7	5Ω								
	010 = 1	$\Omega 00$								
	011 = 1	50Ω								
	1xx = 30	$\Omega 00$								
Bit 2, 1, 0	CT_DA1	TA_2_A, CT_DAT	A_1_A, CT_DAT	A_0_A: CHA da	ta output termina	ation control				
	000 = 5	0 Ω (default)								
	001 = 7	5Ω								
	010 = 1	$\Omega 00$								
	011 = 1	$011 = 150\Omega$								
	1xx = 30	$1xx = 300\Omega$								
CHB Dat	ta Outp	ut Terminati	on Control (05h)						

	•		```				
BIT 7	BIT 6	BIT 5	BIT 4	BIT 3	BIT 2	BIT 1	BIT 0
Х	Х	CT_DCLK_2_B	CT_DCLK_1_B	CT_DCLK_0_B	CT_DATA_2_B	CT_DATA_1_B	CT_DATA_0_B

Bit 7, 6 Don't care

Bit 5, 4, 3 CT_DCLK_2_B, CT_DCLK_1_B, CT_DCLK_0_B: CHB DCLK termination control

 $000 = 50\Omega \text{ (default)}$ $001 = 75\Omega$

- $010 = 100\Omega$
- $010 = 100 \Omega$ $011 = 150 \Omega$
- $1xx = 300\Omega$

Bit 2, 1, 0 CT_DATA_2_B, CT_DATA_1_B, CT_DATA_0_B: CHB data output termination control

- $000 = 50\Omega$ (default)
- $001 = 75\Omega$
- $010 = 100\Omega$
- $011 = 150\Omega$
- $1xx = 300\Omega$

BIT 7		BIT 6	BIT 5	BIT 4	BIT 3	BIT 2	BIT 1	BIT 0		
TEST_PAT	TTERN TEST_DATA FORMAT_1 FORMAT_0				TERM_100	SYNC_MODE	DIV1	DIV0		
Bit 7	O = F	Ramps from 0 to		nary) and repea		formatting appli	, ,	,		
		Data alternate DOR = 0 on bot		[9:0] = 01010	J10101, DOR	= 1, and D[9:	0] = 101	010101		
Bit 6	TEST	[_DATA: Data to	est mode							
	1 = 0	Normal data out	tput (default)							
	1 = (Dutputs test dat	ta pattern							
Bit 5, 4	FOR	MAT_1, FORMA	AT_0: Data num	erical format						
	00 = Two's complement (default)									
	01 =	01 = Offset binary								
	10 =	Gray code								
	11 =	Two's compler	ment							
Bit 3	TERI	M_100: Select 1	100 Ω clock inpu	t termination						
	1 = 0	No termination ((default)							
	1 = 1	100 Ω terminatio	n across differe	ntial clock input	S					
Bit 2	SYN	C_MODE: Divid	ler synchronizat	ion mode select	:					
	0 = Slip mode (Figure 11) (default)									
	1 = E	Edge mode (Fig	gure 12)							
Bit 1, 0	DIV1	, DIV0: Input cl	ock-divider sele	ect						
	00 =	No divider (de	fault)							
	01 =	Divide-by-2								
	10 =	Divide-by-4								
	11 =	No divider								

Reserved (07h)—Do not write to this register

Common Mode (08h)

BIT 6	BIT 5	BIT 4	BIT 3	BIT 2	BIT 1	BIT 0		
B CMI_ADJ_2_B	CMI_ADJ_1_B	CMI_ADJ_0_B	CMI_SELF_A	CMI_ADJ_2_A	CMI_ADJ_1_A	CMI_ADJ_0_A		
CMI_SELF_B: CHB connect input common-mode to analog inputs								
0 = Internal comr	mon-mode volt	age is NOT ap	olied to inputs	(default)				
1 = Internal comr	mon-mode volt	age applied to	analog inputs	through 2k Ω re	sistors			
CMI_ADJ_2_B, C	MI_ADJ_1_B,	CMI_ADJ_0_B:	CHB input co	mmon-mode vo	oltage adjustme	ent		
000 = 0.900V (de	efault)							
001 = 1.050V								
010 = 1.200V								
011 = 1.350V								
100 = 0.900V								
101 = 0.750V								
110 = 0.600V								
111 = 0.450V								
CMI_SELF_A: CH	A connect inp	ut common-mc	de to analog ir	nputs				
0 = Internal comm	mon-mode volt	age is NOT ap	olied to inputs	(default)				
1 = Internal comr	mon-mode volt	age applied to	analog inputs	through 2k Ω re	esistors			
CMI_ADJ_2_A, C	MI_ADJ_1_A,	CMI_ADJ_0_A:	CHA input co	mmon-mode a	djustment			
000 = 0.900V (de	efault)							
001 = 1.050V								
010 = 1.200V								
011 = 1.350V								
100 = 0.900V								
101 = 0.750V								
110 = 0.600V								
111 = 0.450V								
	BIT 6 BIT 6 BIT 6 BIT 6 CMI_ADJ_2_B CMI_SELF_B: CH 0 = Internal command 1 = Internal command CMI_ADJ_2_B, C 000 = 0.900V (detection) 001 = 1.050V 010 = 1.200V 011 = 1.350V 100 = 0.900V 101 = 0.750V 110 = 0.600V 111 = 0.450V CMI_SELF_A: CH 0 = Internal command 1 = Internal command 1 = Internal command 1 = Internal command 1 = Internal command 000 = 0.900V (detection) 001 = 1.050V 010 = 1.200V 011 = 1.350V 100 = 0.900V 101 = 0.750V 101 = 0.750V 101 = 0.750V 110 = 0.600V	BIT 6 BIT 5 B CMI_ADJ_2_B CMI_ADJ_1_B CMI_SELF_B: CHB connect inp 0 = Internal common-mode volt 1 = Internal common-mode volt 1 = Internal common-mode volt CMI_ADJ_2_B, CMI_ADJ_1_B, 000 = 0.900V (default) 001 = 1.050V 010 = 1.200V 011 = 1.350V 100 = 0.900V 101 = 0.750V 110 = 0.600V 111 = 0.450V CMI_SELF_A: CHA connect inp 0 = Internal common-mode volt 1 = Internal common-mode volt 1 = Internal common-mode volt 1 = Internal common-mode volt 001 = 1.200V 011 = 1.350V 001 = 1.200V 011 = 1.350V 001 = 1.200V 011 = 1.350V 010 = 0.900V (default) 001 = 1.200V 011 = 1.350V 100 = 0.900V 101 = 0.750V 101 = 0.750V 101 = 0.750V 101 = 0.750V	BIT 6BIT 5BIT 4BCMI_ADJ_2_BCMI_ADJ_1_BCMI_ADJ_0_BCMI_SELF_B: CHB connect input common-mode0 = Internal common-mode voltage is NOT apple1 = Internal common-mode voltage applied toCMI_ADJ_2_B, CMI_ADJ_1_B, CMI_ADJ_0_B:000 = 0.900V (default)001 = 1.050V010 = 1.200V011 = 1.350V100 = 0.900V101 = 0.750V110 = 0.600V111 = 0.450VCMI_SELF_A: CHA connect input common-mode0 = Internal common-mode voltage applied toCMI_ADJ_2_A, CMI_ADJ_1_A, CMI_ADJ_0_A:000 = 0.900V (default)001 = 1.200V011 = 1.350V100 = 0.900V (default)001 = 1.200V011 = 1.350V010 = 1.200V011 = 1.350V100 = 0.900V (default)001 = 1.200V011 = 1.200V011 = 0.50V100 = 0.900V101 = 0.750V101 = 0.750V101 = 0.750V101 = 0.750V101 = 0.600V	BIT 6BIT 5BIT 4BIT 3BCMI_ADJ_2BCMI_ADJ_1BCMI_ADJ_0BCMI_SELF_ACMI_SELF_B: CHB connect input common-mode to analog in 0 = Internal common-mode voltage is NOT applied to inputs 1 = Internal common-mode voltage applied to analog inputsCMI_ADJ_2_B, CMI_ADJ_1_B, CMI_ADJ_0_B: CHB input col 000 = 0.900V (default)001 = 1.050V010 = 1.200V011 = 1.350V100 = 0.900V101 = 0.750V110 = 0.600V111 = 0.450VCMI_SELF_A: CHA connect input common-mode to analog in 0 = Internal common-mode voltage is NOT applied to inputs 1 = Internal common-mode voltage is NOT applied to inputs 1 = Internal common-mode voltage applied to analog in 0 = 0.900V (default)001 = 1.050VCMI_SELF_A: CHA connect input common-mode to analog in 0 = 0.900V (default)001 = 1.200V011 = 0.750V111 = 0.450VCMI_ADJ_2_A, CMI_ADJ_1_A, CMI_ADJ_0_A: CHA input con 000 = 0.900V (default)001 = 1.050V010 = 1.200V011 = 1.350V100 = 0.900V (default)001 = 1.050V011 = 1.350V100 = 0.900V101 = 0.750V101 = 0.600V	BIT 6 BIT 5 BIT 4 BIT 3 BIT 2 B CMI_ADJ_2_B CMI_ADJ_1_B CMI_ADJ_0_B CMI_SELF_A CMI_ADJ_2_A CMI_SELF_B: CHB connect input common-mode to analog inputs 0 = Internal common-mode voltage applied to inputs (default) 1 = Internal common-mode voltage applied to analog inputs through 2kΩ rec CMI_ADJ_2_B, CMI_ADJ_1_B, CMI_ADJ_0_B: CHB input common-mode voltage applied to analog inputs through 2kΩ rec CMI_ADJ_2_B, CMI_ADJ_1_B, CMI_ADJ_0_B: CHB input common-mode voltage applied to analog inputs through 2kΩ rec CMI_ADJ_2_B, CMI_ADJ_1_B, CMI_ADJ_0_B: CHB input common-mode voltage applied to analog inputs 001 = 1.050V 010 = 1.200V 011 = 0.750V 100 = 0.900V 101 = 0.750V 101 = 0.600V 111 = 0.450V CMI_SELF_A: CHA connect input common-mode to analog inputs 0 = Internal common-mode voltage is NOT applied to inputs (default) 1 1 = Internal common-mode voltage applied to analog inputs through 2kΩ rec CMI_ADJ_2_A, CMI_ADJ_1_A, CMI_ADJ_0_A: CHA input common-mode ac 000 = 0.900V (default) 01 1.050V 01 1.200V 011	B CMI_ADJ_2_B CMI_ADJ_1_B CMI_ADJ_0_B CMI_SELF_A CMI_ADJ_2_A CMI_ADJ_1_A CMI_SELF_B: CHB connect input common-mode to analog inputs 0 = Internal common-mode voltage is NOT applied to inputs (default) 1 1 = Internal common-mode voltage applied to analog inputs through 2kΩ resistors CMI_ADJ_2_B, CMI_ADJ_1_B, CMI_ADJ_0_B: CHB input common-mode voltage adjustme 000 = 0.900V (default) 001 = 1.050V 010 = 1.200V 011 = 1.350V 100 = 0.900V 010 = 0.900V 011 = 0.750V 011 = 0.750V 111 = 0.450V CMI_SELF_A: CHA connect input common-mode to analog inputs 0 = Internal common-mode voltage is NOT applied to inputs (default) 1 = Internal common-mode voltage is NOT applied to inputs (default) 1 = Internal common-mode voltage applied to analog inputs 0 = Internal common-mode voltage applied to analog inputs 0 = Internal common-mode voltage applied to analog inputs (default) 1 = Internal common-mode voltage applied to analog inputs through 2kΩ resistors CMI_ADJ_2_A, CMI_ADJ_1_A, CMI_ADJ_0_A: CHA input common-mode adjustment 000 = 0.900V (default) 01 = 1.200V 011 = 1.350V 001 = 1.200V 011 = 1.350V 00 = 0.900V 011 = 0.750V 101 = 0.750V 101 = 0.750V 101 = 0.750V 101 = 0.600V 101 = 0.600V		

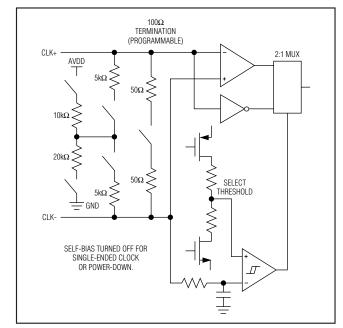
Software Reset (0Ah)

Bit 7–0 SWRESET: Write 5Ah to initiate software reset

MAX19516

Dual-Channel, 10-Bit, 100Msps ADC

Clock Inputs



The input clock interface provides for flexibility in the requirements of the clock driver. The MAX19516 accepts a fully differential clock or single-ended logiclevel clock. For differential clock operation, connect a differential clock to the CLK+ and CLK- inputs. In this mode, the input common mode is established internally to allow for AC-coupling. The differential clock signal can also be DC-coupled if the common mode is constrained to the specified 1V to 1.4V clock input common-mode range. For single-ended operation, connect CLK- to GND and drive the CLK+ input with a logiclevel signal. When the CLK- input is grounded (or pulled below the threshold of the clock mode detection comparator) the differential-to-single-ended conversion stage is disabled and the logic-level inverter path is activated.

Clock Divider

The MAX19516 offers a clock-divider option. Enable clock division either by setting DIV0 and DIV1 through the serial interface; see the Clock Divide/Data

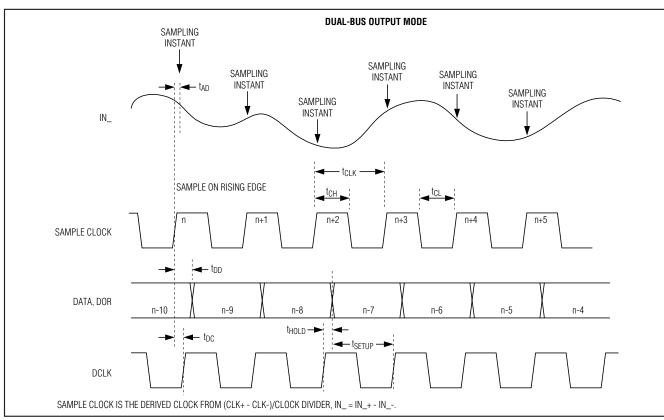


Figure 8. Simplified Clock Input Schematic

Figure 9. Dual-Bus Output Mode Timing

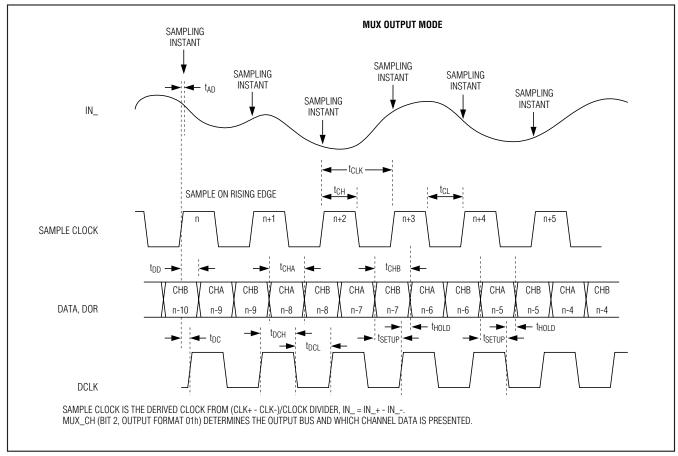


Figure 10. Multiplexed Output Mode Timing

Format/Test Pattern register (06h) for clock-divider options, or in parallel programming configuration (SPEN = 1) by using the DIV input.

System Timing Requirements

Figures 9 and 10 depict the relationship between the clock input and output, analog input, sampling event, and data output. The MAX19516 samples on the rising edge of the sampling clock. Output data is valid on the next rising edge of DCLK after a nine-clock internal latency. For applications where the clock is divided, the sample clock is the divided internal clock derived from:

[(CLK+ - CLK-)/DIVIDER]

Synchronization

When using the clock divider, the phase of the internal clock can be different than that of the FPGA, microcontroller, or other MAX19516s in the system. There are

two mechanisms to synchronize the internal clock: slip synchronization and edge synchronization. Select the synchronization mode using SYNC_MODE (bit 2) in the Clock Divide/Data Format/Test Pattern register (06h) and drive the SYNC input high to synchronize.

Slip Synchronization Mode, SYNC_MODE = 0 (default): On the third rising edge of the input clock (CLK) after the rising edge of SYNC (provided set-up and hold times are met), the divided output is forced to skip a state transition (Figure 11).

Edge Synchronization Mode, SYNC_MODE = 1: On the third rising edge of the input clock (CLK) after the rising edge of SYNC (provided set-up and hold times are met), the divided output is forced to state 0. A divided clock rising edge occurs on the fourth (/2 mode) or fifth (/4 mode) rising edge of CLK, after a valid rising edge of SYNC (Figure 12).

MAX19516

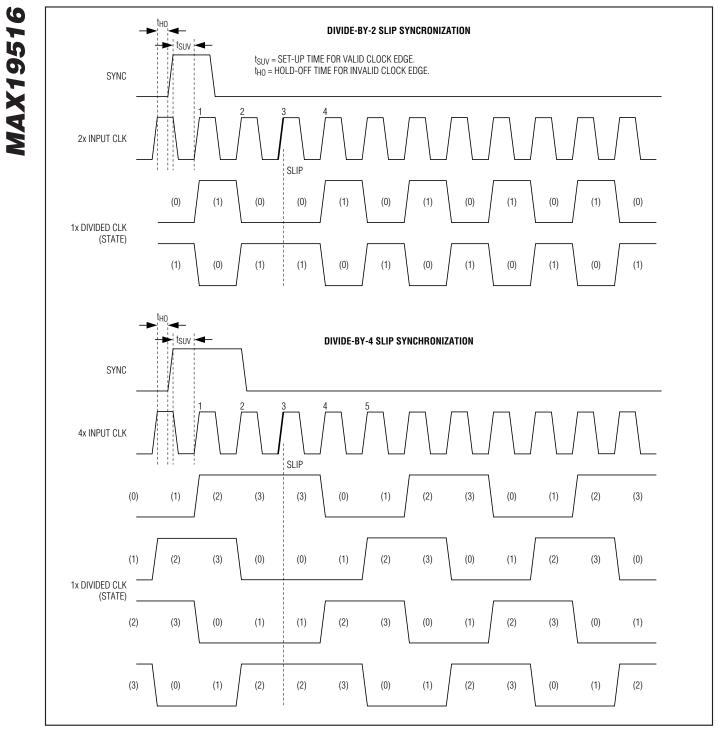


Figure 11. Slip Synchronization Mode

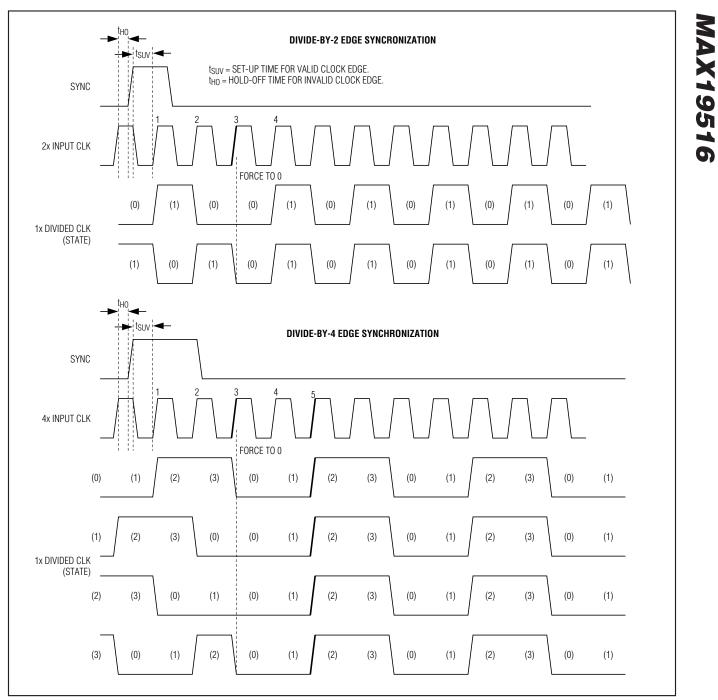


Figure 12. Edge Synchronization Mode

Table 4. Data Timing Controls

MAX19516

DATA TIMING CONTROL	DESCRIPTION
DA_BYPASS	Data aligner bypass. When this control is active (high), data and DCLK delay is reduced by approximately 3.4ns (relative to DA_BYPASS = 0).
DLY_HALF_T	When this control is active, data output is delayed by half clock period (T/2). This control does not delay data output if MUX mode is active.
DTIME<2:0>	Allows adjustment of data output delay in T/16 increments, where T is the sample clock period.
DCLKTIME<2:0>	Provides adjustment of DCLK delay in T/16 increments, where T is the sample clock period. When DTIME and DCLKTIME are adjusted to the same setting, the rising edge of DCLK occurs T/8 prior to data transitions.

Table 5. Data Timing Control DefaultSettings

DATA TIMING CONTROL	DEFAULT DESCRIPTION	
DA_BYPASS	1	Data aligner disabled
DLY_HALF_T	0	No delay
DTIME<2:0>	110	-2T/16 (1.25ns at 100Msps)
DCLKTIME<2:0>	110	-2T/16 (1.25ns at 100Msps)

Digital Outputs

The MAX19516 features a dual CMOS, multiplexable, reversible data bus. In parallel programming mode, configure the data outputs (D0_-D9_) for offset binary, two's complement, or gray code using the FORMAT input. Select multiplexed or dual-bus operation using the OUTSEL input. See the Output Format register (01h) for details on output formatting using the SPI interface. The SPI interface offers additional flexibility where D0_-D9_ are reversed, so the LSB appears at D9_ and the MSB at D0_. OVDD sets the output voltage; set OVDD between 1.8V and 3.3V. The digital outputs feature programmable output impedance from 50Ω to 300Ω . Set the output impedance for each bus using the CH_ Data Output Termination Control registers (04h and 05h).

Programmable Data Timing

The MAX19516 provides programmable data timing control to allow for optimization of timing characteristics to meet the system timing requirements. The timing adjustment feature also allows for ADC performance improvements by shifting the data output transition away from the sampling instant. The data timing control signals are summarized in Table 4. The default settings for timing adjustment controls are given in Table 5. Many applications will not require adjustment from the default settings.

The effects of the data timing adjustment settings are illustrated in Figures 13 and 14. The x axis is sampling rate and the y axis is data delay in units of clock period.

The solid lines are the nominal data timing characteristics for the 14 available states of DTIME and DLY_HALF_T. The heavy line represents the nominal data timing characteristics for the default settings. Note that the default timing adjustment setting for the MAX19516 100Msps ADC results in an additional period of data latency.

Tables 6 and 7 show the recommended timing control settings versus sampling rate.

The nominal data timing characteristics versus sampling rate for these recommended timing adjustment settings are shown in Figures 15 and 16.

When DA_BYPASS = 1, the DCLKTIME delay setting must be equal to or less than the DTIME delay setting, as shown in Table 8.

Power Management

The SHDN input (pin 7) toggles between any two powermanagement states. The Power Management register (00h) defines each power-management state. In default state, SHDN = 1 shuts down the MAX19516 and SHDN = 0 returns to full power. Use of the SHDN input is not required for power management. For either state of SHDN, complete power-management flexibility is provided, including individual ADC channel power-management control, through the Power Management register (00h). The available reduced-power modes are shutdown and standby. In standby mode, the reference and duty-cycle equalizer circuits remain active for rapid wake-up time. In standby mode, the externally applied clock signal must remain active for the duty-cycle equalizer to remain locked. Typical wake-up time from standby mode is 15µs. In shutdown mode, all circuits are turned off except for the reference circuit required for the integrated self-sensing voltage regulator. If the regulator is active, there is additional supply current associated with the regulator circuit when the device is in shutdown. Typical wake-up time from shutdown mode is 5ms, which is dominated by the RC time constant on REFIO.





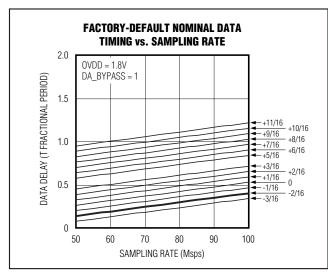


Figure 13. Default Data Timing (VOVDD = 1.8V)

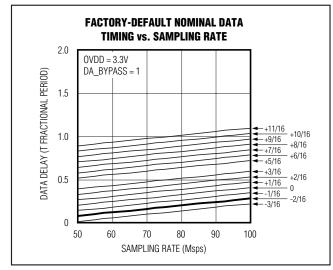


Figure 14. Default Data Timing (VOVDD = 3.3V)

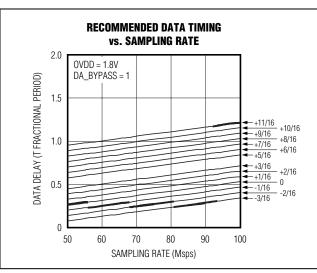


Figure 15. Recommended Data Timing (VOVDD = 1.8V)

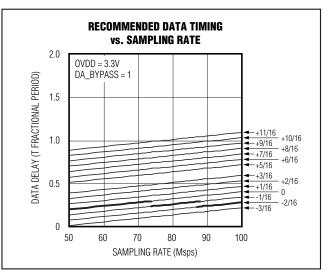


Figure 16. Recommended Data Timing (VOVDD = 3.3V)

Table 6. Recommended Timing Adjustments (V_{OVDD} = 1.8V)

SAMPLING	RATE (Msps)	V _{OVDD} = 1.8V			
FROM	то	DA_BYPASS	DLY_HALF_T	DTIME<2:0>	DCLKTIME<2:0>
50	56	1	0	000	000
56	68	1	0	101	101
68	80	1	0	110	110
80	92	1	0	111	111
92	100	1	1	011	011

VOVDD = 3.3V SAMPLING RATE (Msps) FROM то DA BYPASS DLY_HALF_T DTIME<2:0> DCLKTIME<2:0> 50 73 1 0 000 000 1 73 88 0 101 101 88 100 1 0 110 110

Table 7. Recommended Timing Adjustments (V_{OVDD} = 3.3V)

DTIME<2:0>	ALLOWED DCLKTIME<2:0> SETTINGS	
111 (-3T/16)	111 (-3T/16)	
110 (-2T/16)	110 (-2T/16); 111 (-3T/16)	
101 (-1T/16)	101 (-1T/16); 110 (-2T/16); 111 (-3T/16)	
000 (nominal)	000 (nominal); 101 (-1T/16); 110 (-2T/16); 111 (-3T/16)	
001 (+1T/16)	001 (+1T/16); 000 (nominal); 101 (-1T/16); 110 (-2T/16); 111 (-3T/16)	
010 (+2T/16)	010 (+2T/16); 001 (+1T/16); 000 (nominal); 101 (-1T/16); 110 (-2T/16); 111 (-3T/16)	
011 (+3T/16)	011 (+3T/16); 010 (+2T/16); 001 (+1T/16); 000 (nominal); 101 (-1T/16); 110 (-2T/16); 111 (-3T/16)	

Table 9. Reset Methods

RESET MODE	DESCRIPTION
Power-On Reset	Upon power-up (AVDD supply voltage and clock signal applied), the POR (power-on-reset) circuit initiates a register reset.
Software Reset	Write data 5Ah to address 0Ah to initiate register reset.
Hardware Reset	A register reset is initiated by the falling edge on the SHDN pin when SPEN is high.

Integrated Voltage Regulator

The MAX19516 includes an integrated self-sensing linear voltage regulator on the analog supply (AVDD). See Figure 17. When the applied voltage on AVDD is below 2V, the voltage regulator is bypassed, and the core analog circuitry operates from the externally applied voltage. If the applied voltage on AVDD is higher than 2V, the regulator bypass switches off, and voltage regulator mode is enabled. When in voltage regulation mode, the internal-core analog circuitry operates from a stable 1.8V supply voltage provided by the regulator. The regulator provides an output voltage of 1.8V over a 2.3V to 3.5V AVDD input-voltage range. Since the power-supply current is constant over this voltage range, analog power dissipation is proportional to the applied voltage.

Power-On and Reset

The user-programmable register default settings and other factory-programmed settings are stored in nonvolatile memory. Upon device power-up, these values are loaded into the control registers. This operation occurs after application of supply voltage to AVDD and application of an input clock signal. The register values are retained as long as AVDD is applied. While AVDD is applied, the registers can be reset, which will overwrite all user-programmed registers with the default values. This reset operation can be initiated by software command through the serial-port interface or by hardware control using the SPEN and SHDN inputs. The reset time is proportional to the ADC clock period and requires 85µs at 100Msps. Table 9 summarizes the reset methods.

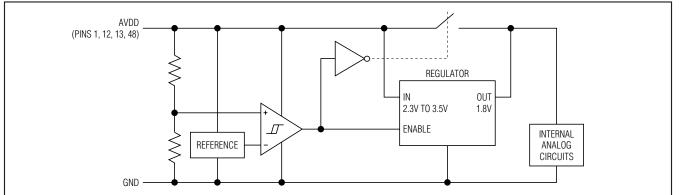


Figure 17. Integrated Voltage Regulator

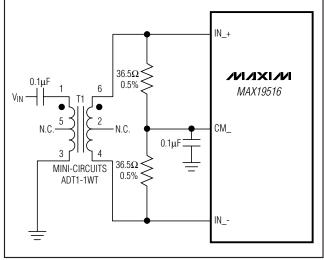


Figure 18. Transformer-Coupled Input Drive for Input Frequencies Up to Nyquist

Applications Information

Analog Inputs

Transformer-Coupled Differential Analog Input

The MAX19516 provides better SFDR and THD with fully differential input signals than a single-ended input drive. In differential input mode, even-order harmonics are lower as both inputs are balanced, and each of the ADC inputs only require half the signal swing compared to single-ended input mode.

An RF transformer (Figure 18) provides an excellent solution for converting a single-ended signal to a fully differential signal. Connecting the center tap of the transformer to CM_ provides a common-mode voltage. The transformer shown has an impedance ratio of 1:1.4. Alternatively, a different step-up transformer can be selected to reduce the drive requirements. A reduced signal swing from the input driver can also improve the overall distortion. The configuration of Figure 18 is good for frequencies up to Nyquist ($f_{CLK}/2$).

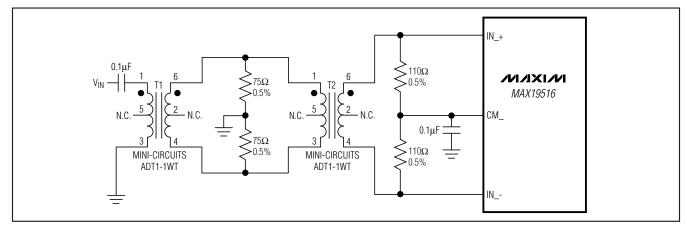


Figure 19. Transformer-Coupled Input Drive for Input Frequencies Beyond Nyquist



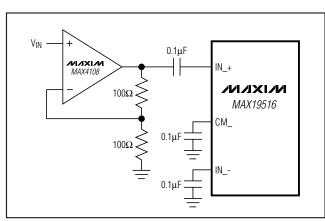


Figure 20. Single-Ended, AC-Coupled Input Drive

The circuit of Figure 19 also converts a single-ended input signal to a fully differential signal. Figure 19 utilizes an additional transformer to improve the commonmode rejection allowing high-frequency signals beyond the Nyquist frequency. A set of 75Ω and 110Ω termination resistors provide an equivalent 50Ω termination to the signal source. The second set of termination resistors connect to CM_ providing the correct input common-mode voltage.

Single-Ended AC-Coupled Input Signal

Figure 20 shows a single-ended, AC-coupled input application. The MAX4108 provides high speed, high bandwidth, low noise, and low distortion to maintain the input signal integrity. Bias voltage is applied to the inputs through internal $2k\Omega$ resistors. See Common Mode register 08h for further details.

DC-Coupled Input

The MAX19516's wide common-mode voltage range (0.4V to 1.4V) allows DC-coupled signals. Ensure that the common-mode voltage remains between 0.4V and 1.4V.

Clock Input

Figure 21 shows a single-ended-to-differential clock input converting circuit.

Grounding, Bypassing, and Board-Layout Considerations

The MAX19516 requires high-speed board-layout design techniques. Locate all bypass capacitors as close as possible to the device, preferably on the same side as the ADC, using surface-mount devices for minimum inductance. Bypass AVDD, OVDD, REFIO, CMA, and CMB with 0.1μ F ceramic capacitors to GND. Multilayer boards with ground and power planes

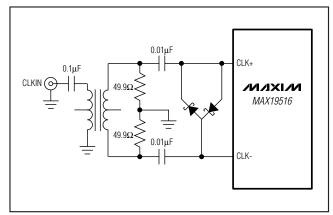


Figure 21. Single-Ended-to-Differential Clock Input

produce the highest level of signal integrity. Route highspeed digital signal traces away from the sensitive analog traces of either channel. Make sure to isolate the analog input lines to each respective converter to minimize channel-to-channel crosstalk. Keep all signal lines short and free of 90° turns.

Definitions

Integral Nonlinearity (INL)

INL is the deviation of the measured transfer function from a best-fit straight line. Worst-case deviation is defined as INL.

Differential Nonlinearity (DNL)

DNL is the difference between the measured transfer function step width and the ideal value of 1 LSB. A DNL error specification of less than 1 LSB guarantees no missing codes and a monotonic transfer function. DNL deviations are measured at each step of the transfer function and the worst-case deviation is defined as DNL.

Offset Error

Offset error is a parameter that indicates how well the actual transfer function matches the ideal transfer function at midscale. Ideally, the midscale transition occurs at 0.5 LSB above midscale. The offset error is the amount of deviation between the measured midscale transition point and the ideal midscale transition point.

Gain Error

Gain error is a figure of merit that indicates how well the slope of the measured transfer function matches the slope of the ideal transfer function based on the specified full-scale input-voltage range. The gain error is defined as the relative error of the measured transfer function and is expressed as a percentage.

Small-Signal Noise Floor (SSNF)

SSNF is the integrated noise and distortion power in the Nyquist band for small-signal inputs. The DC offset is excluded from this noise calculation. For this converter, a small signal is defined as a single tone with an amplitude less than -35dBFS. This parameter captures the thermal and quantization noise characteristics of the converter and can be used to help calculate the overall noise figure of a receive channel. Refer to **www.maxim-ic.com** for application notes on Thermal + Quantization Noise Floor.

Signal-to-Noise Ratio (SNR)

For a waveform perfectly reconstructed from digital samples, the theoretical maximum SNR is the ratio of the full-scale analog input (RMS value) to the RMS quantization error (residual error). The ideal, theoretical minimum analog-to-digital noise is caused by quantization error only and results directly from the ADC's resolution (N bits):

$$SNR[max] = 6.02 \times N + 1.76$$

In reality, there are other noise sources besides quantization noise (e.g., thermal noise, reference noise, clock jitter, etc.). SNR is computed by taking the ratio of the RMS signal to the RMS noise. RMS noise includes all spectral components to the Nyquist frequency excluding the fundamental, the first six harmonics (HD2–HD7), and the DC offset.

$$SNR = 20 \times \log \left(\frac{SIGNAL_{RMS}}{NOISE_{RMS}} \right)$$

Signal-to-Noise and Distortion (SINAD) SINAD is computed by taking the ratio of the RMS signal to the RMS noise plus the RMS distortion. RMS noise includes all spectral components to the Nyquist frequency excluding the fundamental, the first six harmonics (HD2–HD7), and the DC offset. RMS distortion includes the first six harmonics (HD2–HD7).

$$SINAD = 20 \times \log \left(\frac{SIGNAL_{RMS}}{\sqrt{NOISE_{RMS}^2 + DISTORTION_{RMS}^2}} \right)$$

Single-Tone Spurious-Free Dynamic Range (SFDR1 and SFDR2)

SFDR is the ratio expressed in decibels of the RMS amplitude of the fundamental (maximum signal component) to the RMS amplitude of the next largest spurious component, excluding DC offset. SFDR1 reflects the spurious performance based on worst 2nd-order or 3rd-order harmonic distortion. SFDR2 is defined by the worst spurious component excluding 2nd- and 3rd-order harmonics and DC offset.

Total Harmonic Distortion (THD)

THD is the ratio of the RMS of the first six harmonics of the input signal to the fundamental itself. This is expressed as:

THD =
$$20 \times \log \left(\frac{\sqrt{V_2^2 + V_3^2 + V_4^2 + V_5^2 + V_6^2 + V_7^2}}{V_1} \right)$$

where V_1 is the fundamental amplitude and V_2 – V_7 are the amplitudes of the 2nd-order through 7th-order harmonics (HD2–HD7).

Third-Order Intermodulation (IM3)

IM3 is the total power of the third-order intermodulation products to the Nyquist frequency relative to the total input power of the two input tones fIN1 and fIN2. The individual input tone levels are at -7dBFS. The third-order intermodulation products are: $2 \times f_{IN1} - f_{IN2}$, $2 \times f_{IN2} - f_{IN1}$, $2 \times f_{IN1} + f_{IN2}$, $2 \times f_{IN2} + f_{IN1}$.

Aperture Delay

The input signal is sampled on the rising edge of the sampling clock. There is a small delay between the rising edge of the sampling clock and the actual sampling instant, which is defined as aperture delay (t_{AD}).

Aperture Jitter

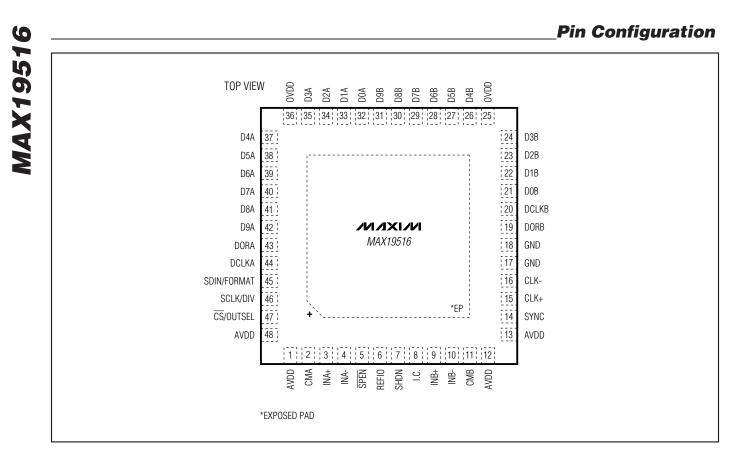
Aperture jitter (t_{AJ}) is defined as the sample-to-sample time variation in the aperture delay.

Overdrive Recovery Time

Chip Information

Overdrive recovery time is the time required for the ADC to recover from an input transient that exceeds the full-scale limits. The specified overdrive recovery time is measured with an input transient that exceeds the full-scale limits by $\pm 10\%$.

PROCESS: CMOS



Package Information

For the latest package outline information and land patterns, go to **www.maxim-ic.com/packages**. Note that a "+", "#", or "-" in the package code indicates RoHS status only. Package drawings may show a different suffix character, but the drawing pertains to the package regardless of RoHS status.

PACKAGE TYPE	PACKAGE CODE	OUTLINE NO.	LAND PATTERN NO.
48 TQFN-EP	T4877+4	<u>21-0144</u>	<u>90-0130</u>

Revision History

REVISION NUMBER	REVISION DATE	DESCRIPTION	PAGES CHANGED
0	7/08	Initial release	—
1	10/08	Corrected error in vertical scale for TOC 32	11
2	9/10	Updated timing characteristics due to CMOS output driver changes	5, 6, 28, 29, 30

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____ 35